

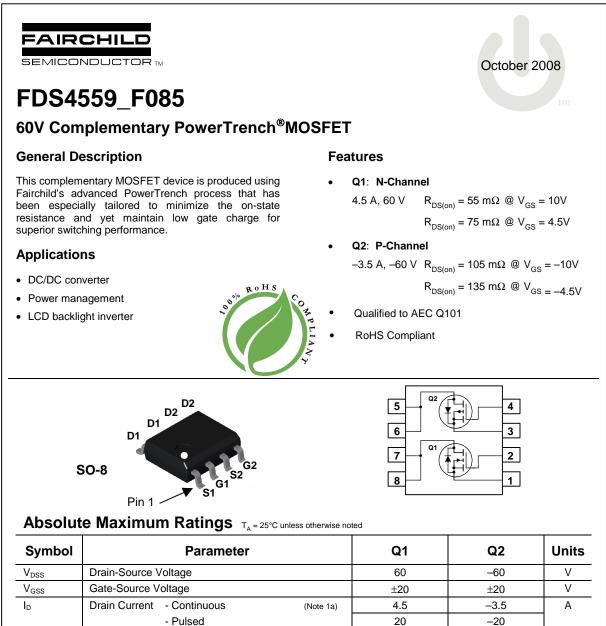
Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at <u>www.onsemi.com</u>

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor dates sheds, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor dates sheds and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use on similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor and its officers, employees, subsidiaries, affliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out or i, directly or indirectly, any lay bed ON Semiconductor and its officers, employees, ween if such claim alleges that ON Semiconductor was negligent regarding the d

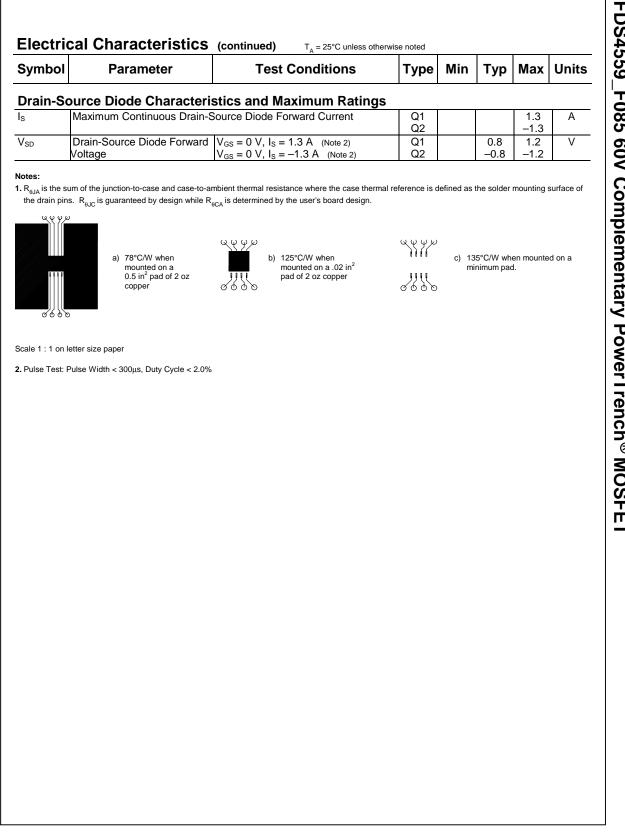


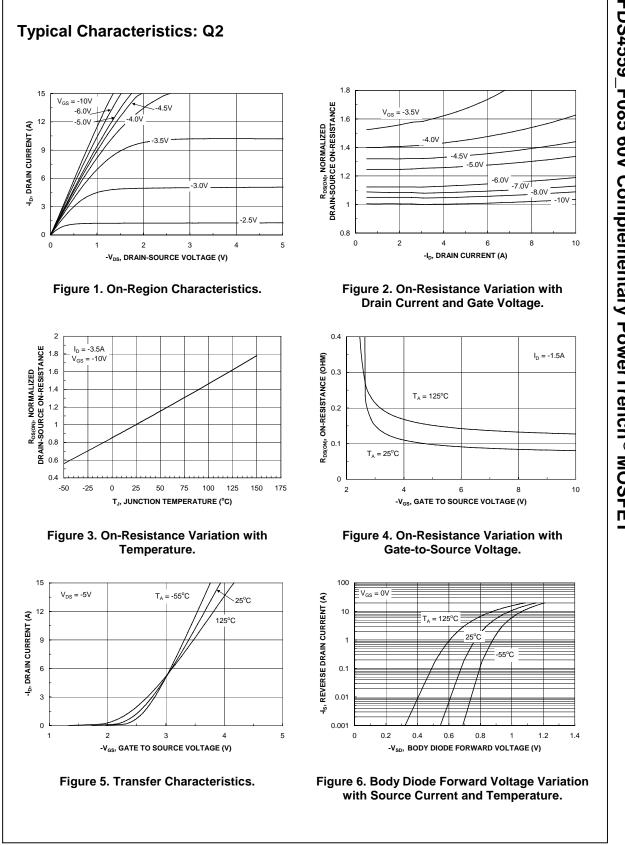
	Parameter				
V _{DSS}	Drain-Source Voltage		60	-60	V
V _{GSS}	Gate-Source Voltage		±20	±20	V
ID	Drain Current - Continuous	(Note 1a)	4.5	-3.5	А
	- Pulsed		20	-20	
PD	Power Dissipation for Dual Operation		2		W
	Power Dissipation for Single Operation	(Note 1a)	1.6		
	(Note 1b)		1.2		
		(Note 1c)		2	
T _J , T _{STG}	Operating and Storage Junction Tempera	ture Range	-55 to	o +150	°C
	Operating and Storage Junction Tempera AI Characteristics Thermal Resistance, Junction-to-Ambien	<u> </u>		o +150 78	°C/W
Therma	al Characteristics	<u> </u>	7		°C/V
Therma R _{θJA} R _{θJC} Packag	Al Characteristics Thermal Resistance, Junction-to-Ambien Thermal Resistance, Junction-to-Case Je Marking and Ordering Inf	(Note 1a) (Note 1)	7	78	

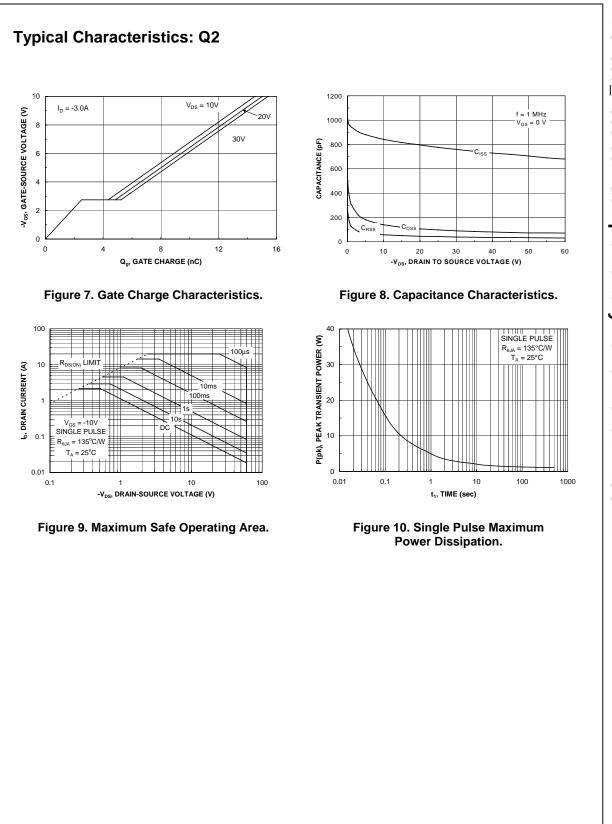
©2008 Fairchild Semiconductor Corporation

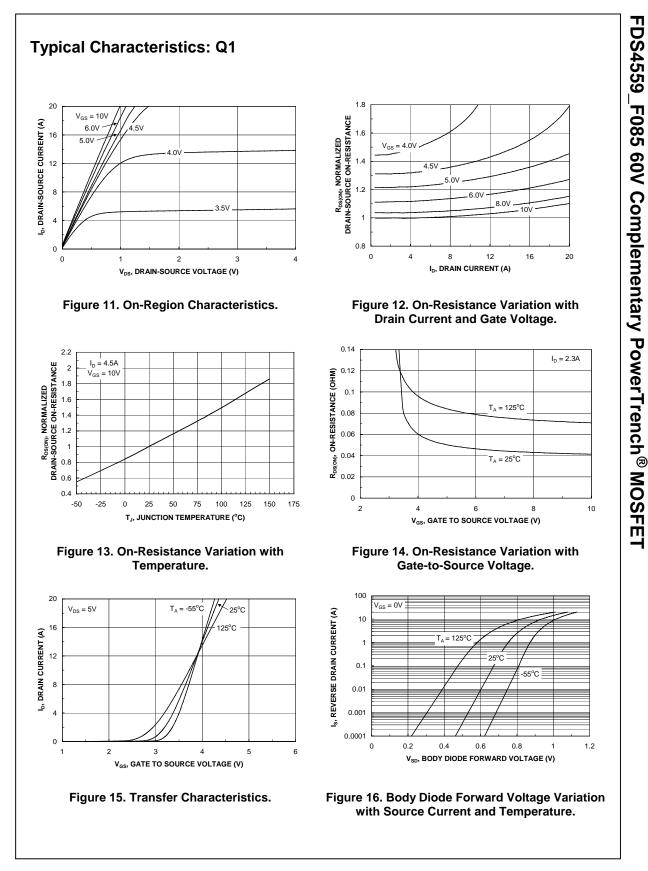
Symbol	Parameter	Test Conditions	Туре	Min	Тур	Max	Units
Drain-So	burce Avalanche Rating	IS (Note 1)					1
W _{DSS}	Single Pulse Drain-Source Avalanche Energy	$V_{DD} = 30 \text{ V}, \qquad I_D = 4.5 \text{ A}$	Q1			90	mJ
I _{AR}	Maximum Drain-Source Avalanche Current		Q1			4.5	A
Off Cha	racteristics	-	-				
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 V, I_D = 250 \mu A$ $V_{GS} = 0 V, I_D = -250 \mu A$	Q1 Q2	60 60			V
ΔBV_{DSS}	Breakdown Voltage	$I_D = 250 \ \mu A$, Referenced to $25^{\circ}C$	Q1		58		mV/°C
ΔΤ」	Temperature Coefficient	$I_D = -250 \mu$ A, Referenced to 25° C	Q2		-49		
DSS	Zero Gate Voltage Drain Current	$V_{DS} = 48 V, V_{GS} = 0 V$ $V_{DS} = -48 V, V_{GS} = 0 V$	Q1 Q2			1 -1	μA
I _{GSS}	Gate-Body Leakage	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$ $V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	Q1 Q2			<u>+</u> 100 +100	nA
On Cha	racteristics (Note 2)	• • • = •					•
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$ $V_{DS} = V_{GS}, I_D = -250 \ \mu A$	Q1 Q2	1 -1	2.2 -1.6	3 _3	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, Referenced to 25°C $I_D = -250 \ \mu$ A, Referenced to 25°C	Q1 Q2		-5.5 4		mV/°C
R _{DS(on)}	Static Drain-Source On-Resistance		Q1		42 72 55	55 94 75	mΩ
		$ \begin{array}{l} V_{\rm GS} = -10 \ V, \ I_{\rm D} = -3.5 \ A \\ V_{\rm GS} = -10 \ V, \ I_{\rm D} = -3.5 \ A, \ T_{\rm J} = 125^{\circ}C \\ V_{\rm GS} = -4.5 \ V, \ I_{\rm D} = -3.1 \ A \end{array} $	Q2		82 130 105	105 190 135	
I _{D(on)}	On-State Drain Current	$V_{GS} = 10 V, V_{DS} = 5 V$ $V_{GS} = -10 V, V_{DS} = -5 V$	Q1 Q2	20 –20			A
g _{FS}	Forward Transconductance	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 4.5 \text{ A}$ $V_{DS} = -5 \text{ V}, \text{ I}_{D} = -3 \text{ 5 A}$	Q1 Q2		14 9		S
Dynami	c Characteristics						
Ciss	Input Capacitance	Q1	Q1		650 750		pF
Coss	Output Capacitance	$V_{DS} = 25 V, V_{GS} = 0 V,$ f = 1.0 MHz Q2	Q2 Q1 Q2		759 80 90		pF
C _{rss}	Reverse Transfer Capacitance	$V_{DS} = -30 \text{ V}, V_{GS} = 0 \text{ V},$ f = 1.0 MHz	Q2 Q1 Q2		35 39		pF
Switchin	g Characteristics (Note 2		Q2		00		
	Turn-On Delay Time	Q1	Q1		11	20	ns
	Turn-On Rise Time	$V_{\text{DD}} = 30 \text{ V}, \text{ I}_{\text{D}} = 1 \text{ A},$ $V_{\text{GS}} = 10 \text{ V}, \text{ R}_{\text{GEN}} = 6 \Omega$	Q2 Q1		7 8	14 18	ns
d(off)	Turn-Off Delay Time		Q2 Q1		10 19	20 35	ns
•	Turn-Off Fall Time	$V_{DD} = -30 \text{ V}, \text{ I}_D = -1 \text{ A},$ $V_{GS} = -10 \text{ V}, \text{ R}_{GEN} = 6 \Omega$	Q2 Q1		19 6	34 15	ns
y ^a .	Total Gate Charge	Q1	Q2 Q1 Q2		12 12.5	22 18 21	nC
Q _{gs}	Gate-Source Charge	V _{DS} = 30 V, I _D = 4.5 A, V _{GS} = 10 V Q2	Q2 Q1 Q2		15 2.4 2.5	21	nC
Q _{gd}	Gate-Drain Charge	$V_{DS} = -30$ V, $I_D = -3.5$ A, $V_{GS} = -10$ V	Q2 Q1 Q2		2.5 2.6 3.0		nC

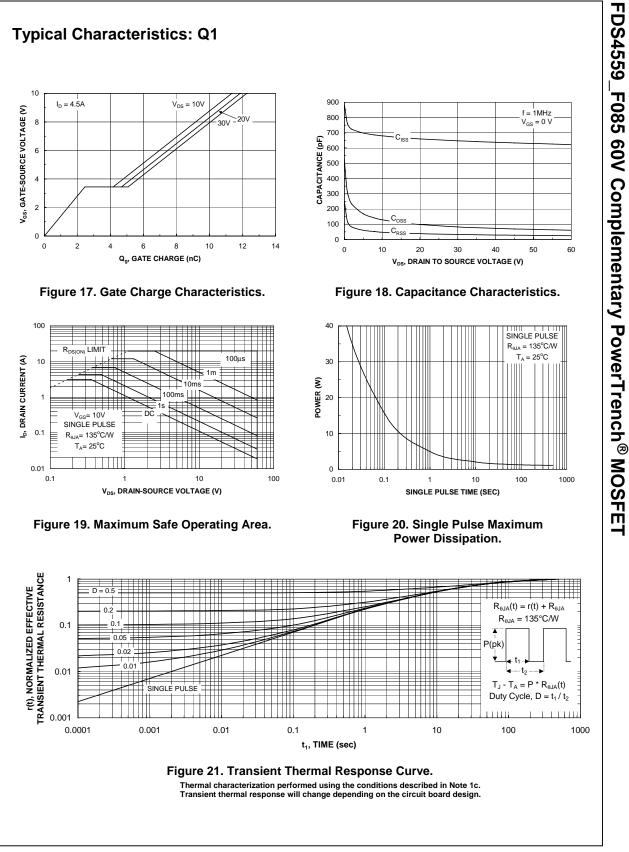
FDS4559_F085 60V Complementary PowerTrench[®] MOSFET

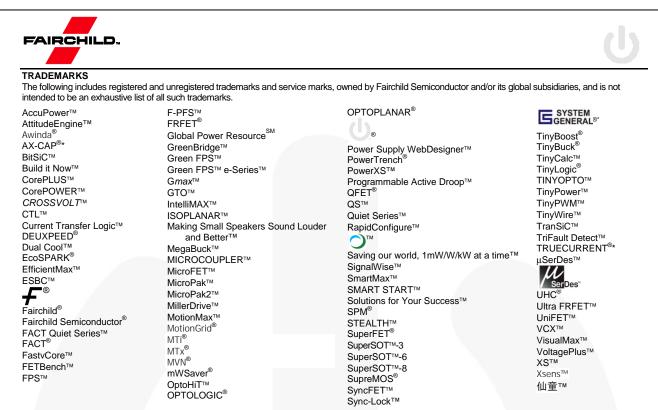












* Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. TO OBTAIN THE LATEST, MOST UP-TO-DATE DATASHEET AND PRODUCT INFORMATION, VISIT OUR WEBSITE AT <u>HTTP://WWW.FAIRCHILDSEMI.COM</u>, FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

AUTHORIZED USE

Unless otherwise specified in this data sheet, this product is a standard commercial product and is not intended for use in applications that require extraordinary levels of quality and reliability. This product may not be used in the following applications, unless specifically approved in writing by a Fairchild officer: (1) automotive or other transportation, (2) military/aerospace, (3) any safety critical application – including life critical medical equipment – where the failure of the Fairchild product reasonably would be expected to result in personal injury, death or property damage. Customer's use of this product is subject to agreement of this Authorized Use policy. In the event of an unauthorized use of Fairchild's product, Fairchild accepts no liability in the event of product failure. In other respects, this product shall be subject to Fairchild's Worldwide Terms and Conditions of Sale, unless a separate agreement has been signed by both Parties.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com, under Terms of Use

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS

Definition of Terms						
Datasheet Identification	Product Status	Definition				
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.				
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.				
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.				
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.				

Rev. 176

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor has against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death ass

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

© Semiconductor Components Industries, LLC